### Low Noise Amplifier with Bypass for 5 GHz band

#### ■ FEATURES

- Wide frequency range 4900MHz to 5950MHz
- Low operating voltage 1.5V to 3.3 V
- Low current 5.0/3.5mA typ. @ V<sub>DD</sub>=2.8/1.8V
  High gain
- 15.0dB typ. @ V<sub>DD</sub>=2.8V, f<sub>RF</sub>=5500 MHz
- Low noise figure
  - 1.1dB typ. @ V<sub>DD</sub>=2.8V, f<sub>RF</sub>=5500MHz
- High IIP3
- +2.0dBm typ.@V<sub>DD</sub>=2.8V,f<sub>RF</sub>=5500MHz+5501MHz • Low insertion loss (bypass mode)
- 3.5dB typ.@ V<sub>DD</sub>=2.8V, f<sub>RF</sub>=5500MHz
- Ultra-small package size 1.1 x 0.7 x 0.37mm typ.
- RoHS compliant and Halogen Free, MSL1

#### ■ GENERAL DESCRIPTION

NJG1182UX2 is low noise amplifier with bypass switch for 5GHz application such as LTE-U/LAA, which covers frequency from 4900MHz to 5950MHz.

NJG1182UX2 is able to select LNA active mode or bypass mode by low control voltage. This LNA achieves low noise figure and high linearity.

Integrated ESD protection device on each port achieves excellent ESD robustness.

A very small and ultra-thin package EPFFP6-X2 is adopted.

#### TRUTH TABLE

#### "H"=V<sub>CTL(H)</sub>, "L"=V<sub>CTL(L)</sub>

| VCTL | Mode            |
|------|-----------------|
| Н    | LNA active mode |
| L    | Bypass mode     |

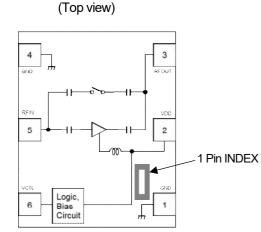
#### PIN CONFIGURATION

| PIN NO. | SYMBOL | DESCRIPTION     |
|---------|--------|-----------------|
| 1       | GND    | Ground          |
| 2       | VDD    | Power supply    |
| 3       | RFOUT  | RF output       |
| 4       | GND    | Ground          |
| 5       | RFIN   | RF input        |
| 6       | VCTL   | Control voltage |

# APPLICATION LTE-U/LAA receive application

- WiMAX 5GHz receive application
- WLAN 5GHz receive application
- RF front-end modules, data cards, and other mobile applications

#### ■ BLOCK DIAGRAM (EPFFP6-X2)



#### PRODUCT NAME INFORMATION

| <u>NJG1182</u> | <u>UX2</u> | <u>(TE1)</u> |
|----------------|------------|--------------|
|                |            | I            |
| Part number    | Package    | Taping form  |

#### ORDERING INFORMATION

| PART NUMBER | PACKAGE<br>OUTLINE | RoHS | HALOGEN-<br>FREE | TERMINAL<br>FINISH | MARKING | WEIGHT<br>(mg) | MOQ (pcs.) |
|-------------|--------------------|------|------------------|--------------------|---------|----------------|------------|
| NJG1182UX2  | EPFFP6-X2          | Yes  | Yes              | Ni/Pd/Au           | 5       | 0.7            | 5,000      |

#### ■ ABSOLUTE MAXIMUM RATINGS

|                       |                  | T <sub>a</sub> = 25°C, Z | $G_{\rm s} = Z_{\rm l} = 50 \ \Omega$ |
|-----------------------|------------------|--------------------------|---------------------------------------|
| PARAMETER             | SYMBOL           | RATINGS                  | UNIT                                  |
| Operating voltage     | VDD              | 5.0                      | V                                     |
| Control voltage       | VCTL             | 5.0                      | V                                     |
| Input power           | Pin              | +15 <sup>(1)</sup>       | dBm                                   |
| Power dissipation     | PD               | 430 <sup>(2)</sup>       | mW                                    |
| Operating temperature | T <sub>opr</sub> | -40 to +105              | °C                                    |
| Storage temperature   | T <sub>stg</sub> | -55 to +150              | °C                                    |

(1): V<sub>DD</sub>=2.8V

(2): 4-layer FR4 PCB with through-hole (101.5x114.5mm),  $T_j$ =150°C

#### ■ ELECTRICAL CHARACTERISTICS 1 (DC)

|                        | General condition: $T_a$ =+25°C, with application circ |                                   |      |      |      |      |  |
|------------------------|--|-----------------------------------|------|------|------|------|--|
| PARAMETER              | SYMBOL   | TEST CONDITION                    | MIN. | TYP. | MAX. | UNIT |  |
| Operating voltage      | V <sub>DD</sub>  |                                   | 1.5  | -    | 3.3  | V    |  |
| Control voltage (High) | Vctl(H)  |                                   | 1.3  | 1.8  | 3.3  | V    |  |
| Control voltage (Low)  | V <sub>CTL(L)</sub>                                    |                                   | 0    | 0    | 0.3  | V    |  |
| Operating current 1    | I <sub>DD</sub> 1                                      | RF OFF,<br>Vdd=2.8V, Vctl=1.8V    | -    | 5.0  | 8.0  | mA   |  |
| Operating current 2    | I <sub>DD</sub> 2                                      | RF OFF,<br>Vdd=1.8V, Vcт.=1.8V    | -    | 3.5  | 8.0  | mA   |  |
| Operating current 3    | IDD3   | RF OFF,<br>Vdd=2.8V, Vctl=0V      | -    | 20   | 60   | μA   |  |
| Operating current 4    | I <sub>DD</sub> 4                                      | RF OFF,<br>Vdd=1.8V, Vcт.=0V      | -    | 10   | 60   | μA   |  |
| Control current        | Іст∟   | RF OFF,<br>V <sub>CTL</sub> =1.8V | -    | 7    | 20   | μA   |  |

#### ■ELECTRICAL CHARACTERISTICS 2 (LNA active mode)

| General condition: $V_{DD}$ =2.8V, $V_{CTL}$ =1.8V, $f_{RF}$ =5500MHz, $T_a$ =+25°C, $Z_s$ = $Z_i$ =50 $\Omega$ , with | application circuit |
|--|---------------------|
|  | application of our  |

|   |                   |  | -     |       |      |      |
|---|-------------------|--|-------|-------|------|------|
| PARAMETER   | SYMBOL            | TEST CONDITION   | MIN.  | TYP.  | MAX. | UNIT |
| Small signal gain1                                  | Gain1             | Exclude PCB & connector losses *1  | 12.0  | 15.0  | 17.5 | dB   |
| Noise figure1                                       | NF1               | Exclude PCB & connector losses *2  | -     | 1.1   | 1.7  | dB   |
| Input power at 1dB<br>gain compression<br>point1(1) | P-1dB(IN)<br>1(1) |  | -16.0 | -11.0 | -    | dBm  |
| Input 3rd order<br>intercept point1(1)              | IIP3_1(1)         | f1=f <sub>RF</sub> , f2= f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-30dBm | -5.0  | +2.0  | -    | dBm  |
| RF IN<br>return loss1(1)                            | RLi1(1)           |  | 8.0   | 16.0  | -    | dB   |
| RF OUT<br>return loss1(1)                           | RLo1(1)           |  | 5.0   | 8.0   | -    | dB   |
| Gain settling<br>time1(1)                           | Ts1(1)            | Bypass to LNA active mode to be within 1 dB of the final gain              | -     | 1.0   | 2.5  | μs   |
| Gain settling<br>time1(2)                           | Ts1(2)            | LNA active to Bypass mode to be within 1 dB of the final insertion loss    | -     | 0.8   | 2.5  | μs   |

\*1: PCB and connector losses: 0.64 dB

\*2: PCB and connector losses: 0.30 dB

#### ■ ELECTRICAL CHARACTERISTICS 3 (Bypass mode)

General condition:  $V_{DD}$ =2.8V,  $V_{CTL}$ =0V,  $f_{RF}$ =5500MHz,  $T_a$ =+25°C,  $Z_s$ = $Z_I$ =50 $\Omega$ , with application circuit

| PARAMETER                                      | SYMBOL            | TEST CONDITION  | MIN.  | TYP.  | MAX. | UNIT |
|--|-------------------|---|-------|-------|------|------|
| Insertion Loss1                                | Loss1             | Exclude PCB & connector losses *1   | -     | 3.5   | 5.0  | dB   |
| Input power at 1dB<br>compression<br>point1(2) | P-1dB(IN)<br>1(2) |   | +2.0  | +7.5  | -    | dBm  |
| Input 3rd order<br>intercept point1(2)         | IIP3_1(2)         | f1=f <sub>RF</sub> , f2=f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-10dBm | +10.0 | +18.0 | -    | dBm  |
| RF IN<br>return loss1(2)                       | RLi1(2)           |   | 6.0   | 13.0  | -    | dB   |
| RF OUT<br>return loss1(2)                      | RLo1(2)           |   | 4.0   | 6.0   | -    | dB   |

\*1: PCB and connector losses: 0.64 dB

#### ■ ELECTRICAL CHARACTERISTICS 4 (LNA active mode)

| PARAMETER   | SYMBOL            | TEST CONDITION   | MIN. | TYP.  | MAX. | UNIT |
|---|-------------------|--|------|-------|------|------|
| Small signal gain2                                  | Gain2             | Exclude PCB & connector losses *1  | -    | 14.5  | -    | dB   |
| Noise figure2                                       | NF2               | Exclude PCB & connector losses *2  | -    | 1.4   | -    | dB   |
| Input power at 1dB<br>gain compression<br>point2(1) | P-1dB(IN)<br>2(1) |  |      | -13.0 |      | dBm  |
| Input 3rd order<br>intercept point2(1)              | IIP3_2(1)         | f1=f <sub>RF</sub> , f2= f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-30dBm | -    | -1.0  | -    | dBm  |
| RF IN<br>return loss2(1)                            | RLi2(1)           |  | -    | 11.0  | -    | dB   |
| RF OUT<br>return loss2(1)                           | RLo2(1)           |  | -    | 8.0   | -    | dB   |
| Gain settling<br>time2(1)                           | Ts2(1)            | Bypass to LNA active mode<br>To be within 1 dB of the final gain           | -    | 2.0   | -    | μs   |
| Gain settling<br>time2(2)                           | Ts2(2)            | LNA active to Bypass mode<br>To be within 1 dB of the final insertion loss | -    | 0.8   | -    | μs   |

\*1: PCB and connector losses: 0.64 dB

\*2: PCB and connector losses: 0.30 dB

#### ■ ELECTRICAL CHARACTERISTICS 5 (Bypass mode)

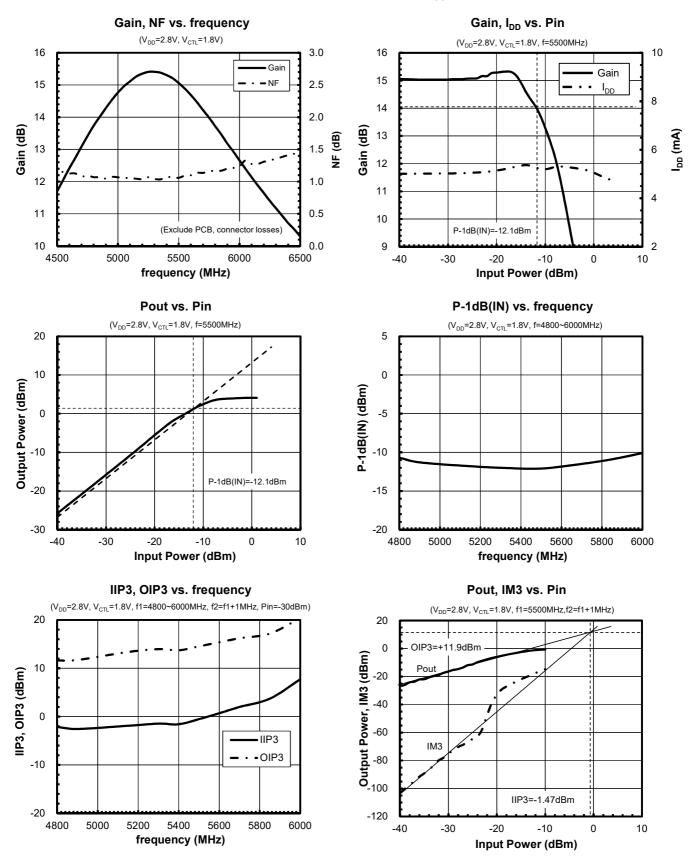
General condition:  $V_{DD}$ =1.8V,  $V_{CTL}$ =0V,  $f_{RF}$ =5500MHz,  $T_a$ =+25°C,  $Z_s$ =Zi=50 $\Omega$ , with application circuit

| PARAMETER                                      | SYMBOL            | TEST CONDITION  | MIN. | TYP.  | MAX. | UNIT |
|--|-------------------|---|------|-------|------|------|
| Insertion Loss2                                | Loss2             | Exclude PCB & connector losses *1   | -    | 3.5   | -    | dB   |
| Input power at 1dB<br>compression<br>point2(2) | P-1dB(IN)<br>2(2) |   | -    | +7.0  | -    | dBm  |
| Input 3rd order<br>_intercept point2(2)        | IIP3_2(2)         | f1=f <sub>RF</sub> , f2=f <sub>RF</sub> +1MHz,<br>P <sub>IN</sub> =-10dBm | -    | +18.0 | -    | dBm  |
| RF IN<br>return loss2(2)                       | RLi2(2)           |   | -    | 13.0  | -    | dB   |
| RF OUT<br>return loss2(2)                      | RLo2(2)           |   | -    | 7.0   | -    | dB   |

\*1: PCB and connector losses: 0.64 dB

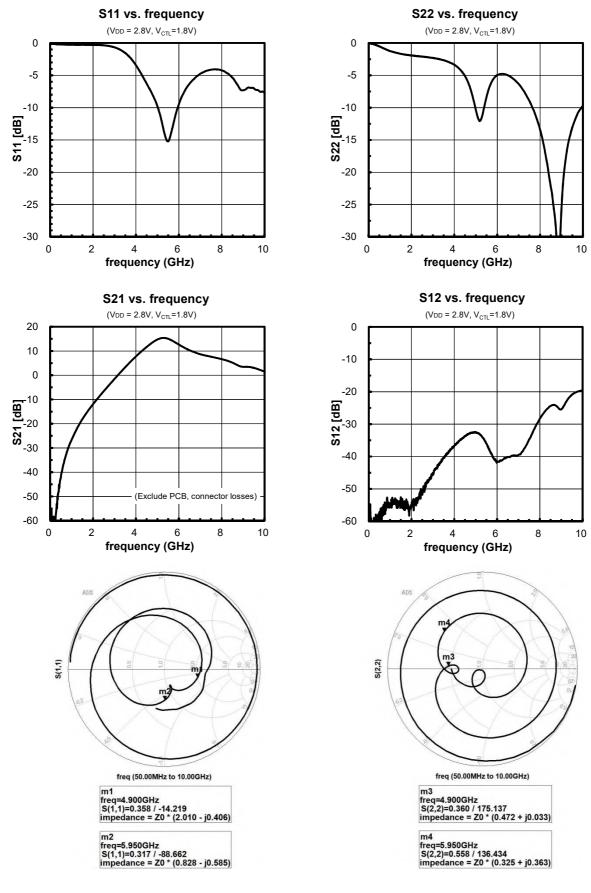
#### ■ ELECTRICAL CHARACTERISTICS (LNA active mode)

Conditions:  $V_{DD}$ =2.8V,  $V_{CTL}$ =1.8V,  $f_{RF}$ =5500MHz,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ , with application circuit



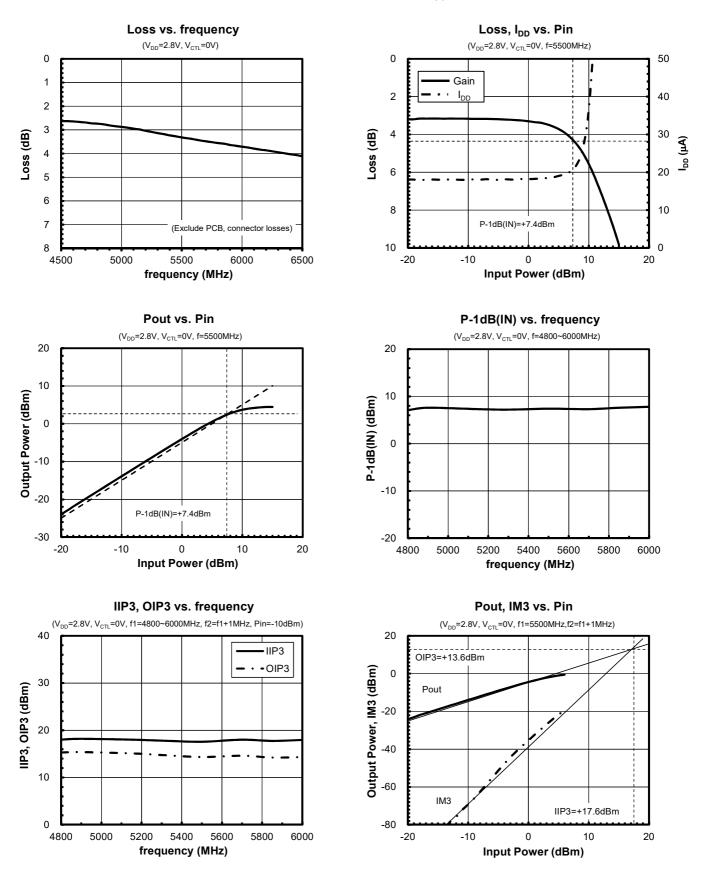
#### ■ ELECTRICAL CHARACTERISTICS (LNA active mode)

Conditions: V<sub>DD</sub>=2.8V, V<sub>CTL</sub>=1.8V, f<sub>RF</sub>=50MHz to 10000MHz, T<sub>a</sub>=+25°C, Z<sub>s</sub>=Z<sub>I</sub>=50Ω, with application circuit



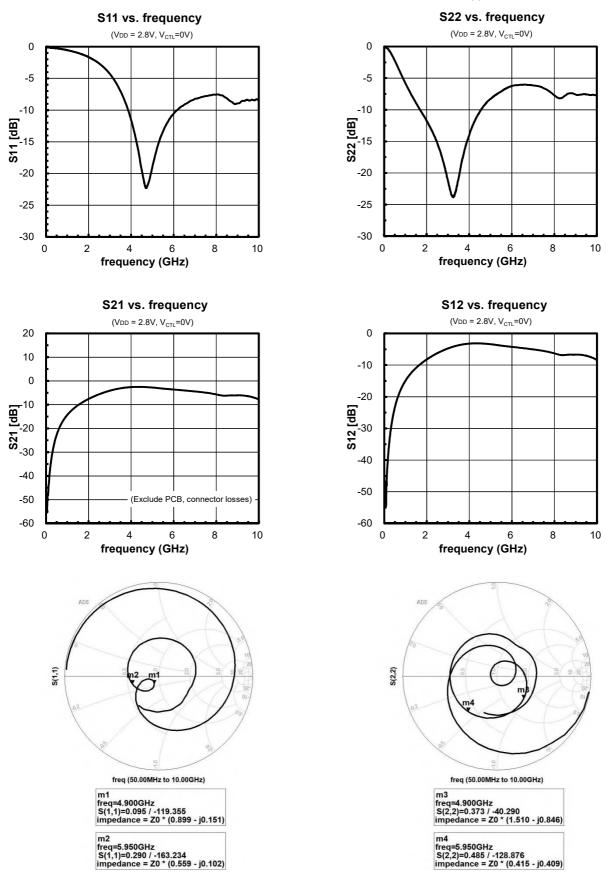
#### ■ ELECTRICAL CHARACTERISTICS (Bypass mode)

Conditions:  $V_{DD}$ =2.8V,  $V_{CTL}$ =0V,  $f_{RF}$ =5500MHz,  $T_a$ =+25°C,  $Z_s$ = $Z_l$ =50 $\Omega$ , with application circuit



#### ■ ELECTRICAL CHARACTERISTICS (Bypass mode)

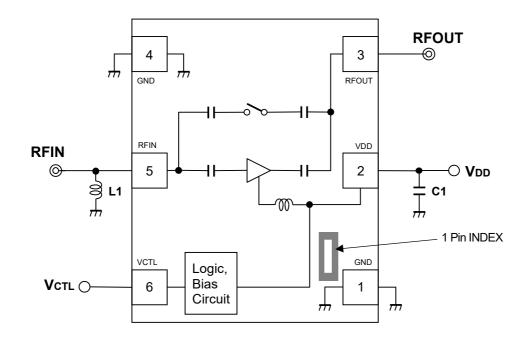
Conditions:  $V_{DD}$ =2.8V,  $V_{CTL}$ =0V,  $f_{RF}$ =50MHz to 10000MHz,  $T_a$ =+25°C,  $Z_s$ = $Z_i$ =50 $\Omega$ , with application circuit



### NJG1182UX2

#### ■ APPLICATION CIRCUIT

(Top view)



#### Parts list

| Part ID | Value  | Notes             |
|---------|--------|-------------------|
| L1      | 1.6nH  | LQP03TN_02 series |
|         |        | (MURATA)          |
| C1      | 4700pF | GRM03 series      |
|         |        | (MURATA)          |

#### ■ NF MEASUREMENT BLOCK DIAGRAM

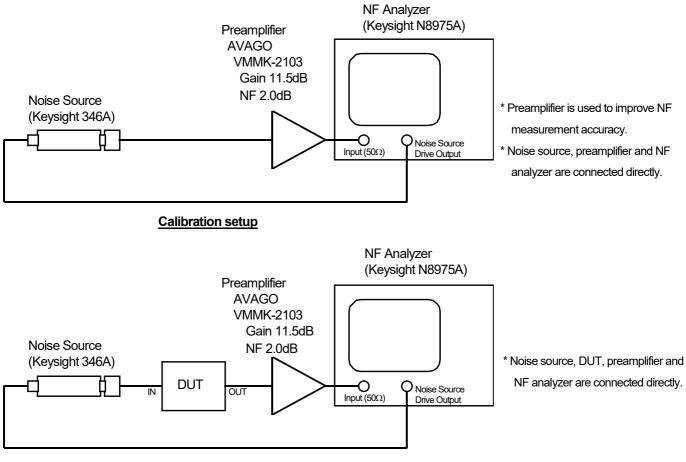
#### Measuring instruments

| NF Analyzer  | : Keysight N8975A |
|--------------|-------------------|
| Noise Source | : Keysight 346A   |

#### Setting the NF analyzer

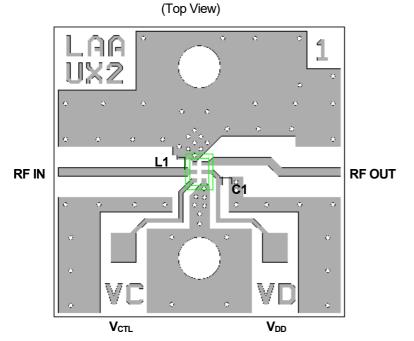
| Measurement mode form |                     |  |
|-----------------------|---------------------|--|
| Device under test     | : Amplifier         |  |
| System downconverter  | : off               |  |
| Mode setup form       |                     |  |
| Sideband              | : LSB               |  |
| Averages              | : 16                |  |
| Average mode          | : Point             |  |
| Bandwidth             | : 4MHz              |  |
| Loss comp             | : off               |  |
| Tcold                 | : setting the tempe |  |

setting the temperature of noise source (305.15K)



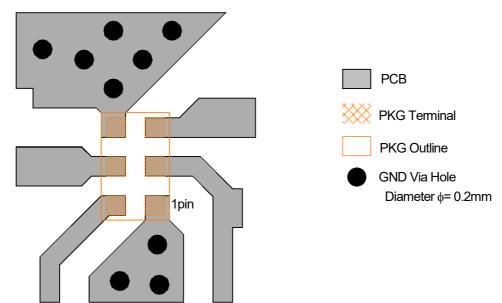
Measurement Setup

#### EVALUATION BOARD



PCB Information Substrate: FR-4 Thickness: 0.2mm Microstrip line width: 0.4mm (Z<sub>0</sub>=50Ω) Size: 14.0mm x 14.0mm

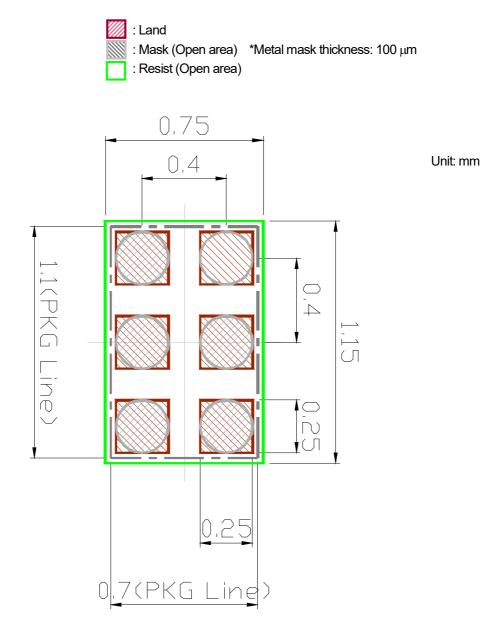
#### < PCB LAYOUT GUIDELINE>



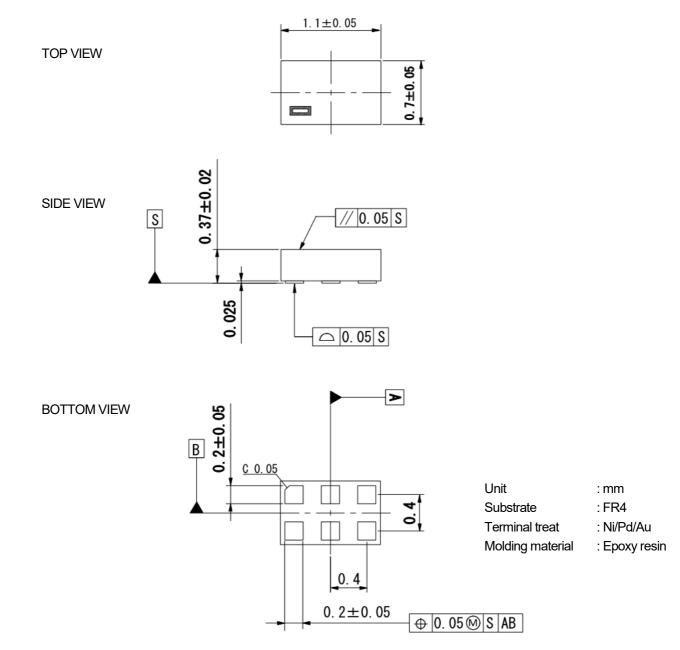
#### PRECAUTIONS

- All external parts should be placed as close as possible to the IC.
- For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the IC.

#### ■ RECOMMENDED FOOTPRINT PATTERN (EPFFP6-X2)

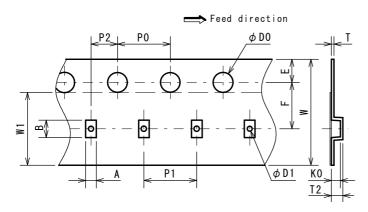


#### ■ PACKAGE OUTLINE (EPFFP6-X2)



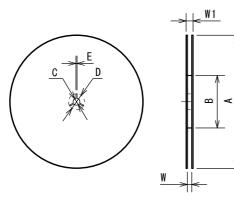
## NJG1182UX2

#### PACKING SPECIFICATION (EPFFP6-X2) TAPING DIMENSIONS



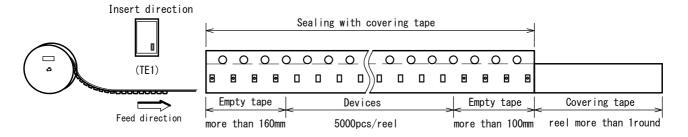
| SYMBOL | DIMENSION                           | REMARKS           |
|--------|-------------------------------------|-------------------|
| Α      | 0.85±0.03                           | BOTTOM DIMENSION  |
| В      | 1.25±0.03                           | BOTTOM DIMENSION  |
| DO     | 1.5 <sup>+0.1</sup>                 |                   |
| D1     | 0.35±0.05                           |                   |
| E      | 1.75±0.1                            |                   |
| F      | 3.5±0.05                            |                   |
| P0     | 4.0±0.1                             |                   |
| P1     | 4.0±0.1                             |                   |
| P2     | 2.0±0.05                            |                   |
| T      | 0.2±0.05                            |                   |
| T2     | 0. 75                               |                   |
| KO     | 0.45±0.05                           |                   |
| W      | 8.0 <sup>+0.3</sup> <sub>-0.1</sub> |                   |
| W1     | 5.5                                 | THICKNESS 0. 1max |

**REEL DIMENSIONS** 

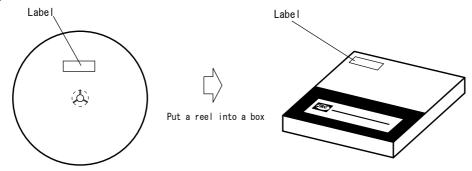


| SYMBOL | DIMENSION          |
|--------|--------------------|
| Α      | φ180 _0_5          |
| В      | $\phi 60^{+1}_{0}$ |
| C      | φ 13±0.2           |
| D      | φ 21±0.8           |
| E      | 2±0.5              |
| W      | 9 <sup>+0.3</sup>  |
| W1     | 11.4±0.1           |

TAPING STATE



PACKING STATE



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  - Various Safety Devices
  - Traffic control system
  - Combustion equipment

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- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
  - 8-1. Quality Warranty Period

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.

8-2. Quality Warranty Remedies

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

- Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
- 8-3. Remedies after Quality Warranty Period

With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.

- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



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